#### **Status of the low mass cables.**



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GSI Helmholtzzentrum, Collaboration meeting

#### Test on a copper cable 1m long.

The defined model for the device under simulation is working quite well, as confirmed by the measurement.



#### simulation

#### measurement

at data rate s=1.25Gb/s

## Report on the prototype production.

Two requests for the same aluminum cable layout, to two different suppliers.

 Techfab (near Torino): order sent on June 09, only one sample received, technology with aluminum deposition, presently not reliable for bonding.



 De Oliveira (at Cern): order sent on October 09, no sample received yet, technology with laminated aluminum, declared easy to bond.

### Specification of the low mass cable.

Made by Techfab on a kapton support, with a folded layout.

track length [m] track width [μm] track thickness [μm] differential impedance [Ω] linear resistance [Ω]

#### requested obtained 1.0 .9 150 120 5.0 6.5 100 110 37 46

## Total jitter with pulser only.



#### total jitter T<sub>i</sub>=58.2ps @ s=1.06Gb/s

The results, coming out from the measurements, are compatible with the data sheet specifications.

# Total jitter with copper PCB (I=1m).



#### total jitter T<sub>i</sub>=116ps @ s=1.06Gb/s

Owing to the large capacitive load, the rise and fall time are getting worse but the eye diagram is still open enough.

## Total jitter with board in loopback.



### total jitter T<sub>j</sub>=107ps @ s=1.06Gb/s

In this case the signal is going directly from the driver to the receiver chip, covering few centimeters of PCB.

# Total jitter with aluminum cable (I=1m).



### total jitter T<sub>j</sub>=171ps @ s=1.06Gb/s

The signal is going through the aluminum cable, but the transition time is stable because of the receiver chip.

### Comparison between the different setup.

The total jitter is represented vs the data rate: the worsening around 2Gb/s is probably due to the transceiver chips.



De Remigis

## Short summary.

The cable production required a very long time: 6month at Techfab; greater than 4month at Cern (not delivered yet).

At present, the surface treatment is not optimized and the bonding yield is not compatible with a mass production.

The test for the evaluation of new surface treatment is in progress, to get a more reliable bonding.

The very preliminary results show a good behaviour, up to a data rate >1Gb/s.

The setup will be modified (driver and receiver) to allow the electrical test up to a data rate >2Gb/s.